

# **Excellent Integrated System Limited**

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

ON Semiconductor MBR20100CT

For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>



# MBR2080CTG, MBR2090CTG, MBR20100CTG

# Switch-mode Power Rectifiers

This series uses the Schottky Barrier principle with a platinum barrier metal. These state-of-the-art devices have the following features:

#### **Features**

- 20 A Total (10 A Per Diode Leg)
- Guard-Ring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Power Loss/High Efficiency
- High Surge Capacity
- Low Stored Charge Majority Carrier Conduction
- Shipped 50 units per plastic tube
- These Devices are Pb-Free and are RoHS Compliant\*

#### **Mechanical Characteristics:**

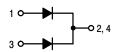
- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



#### ON Semiconductor®

www.onsemi.com

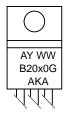
## SCHOTTKY BARRIER RECTIFIERS 20 AMPERES 80-100 VOLTS





TO-220 CASE 221A STYLE 6

#### **MARKING DIAGRAM**



A = Assembly Location

Y = Year

WW = Work Week

B20x0 = Device Code

x = 8, 9 or 10

G = Pb-Free Device

AKA = Polarity Designator

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### **Distributor of ON Semiconductor: Excellent Integrated System Limited**

Datasheet of MBR20100CT - DIODE ARRAY SCHOTTKY 100V TO220

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### MBR2080CTG, MBR2090CTG, MBR20100CTG

#### MAXIMUM RATINGS (Per Diode Leg)

		MBR			
Rating	Symbol	2080CT	2090CT	20100CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	80	90	100	V
Average Rectified Forward Current (Rated V <sub>R</sub> ) T <sub>C</sub> = 133°C	I <sub>F(AV)</sub>	10		Α	
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz) T <sub>C</sub> = 133°C	I <sub>FRM</sub>	20		Α	
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	150		A	
Peak Repetitive Reverse Surge Current (2.0 μs, 1.0 kHz)	I <sub>RRM</sub>		0.5		Α
Operating Junction Temperature (Note 1)	TJ		- 65 to +175	5	°C
Storage Temperature	T <sub>stg</sub>	- 65 to +175		°C	
Voltage Rate of Change (Rated V <sub>R</sub> )	dv/dt		10,000		V/μs

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance Junction-to-Case  Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$	2.0 60	°C/W

#### **ELECTRICAL CHARACTERISTICS** (Per Diode Leg)

Characteristic	Symbol	Value	Unit
$\label{eq:maximum Instantaneous Forward Voltage (Note 2)} \begin{subarray}{ll} (i_F = 10 \text{ Amps, } T_C = 125^\circ\text{C}) \\ (i_F = 10 \text{ Amps, } T_C = 25^\circ\text{C}) \\ (i_F = 20 \text{ Amps, } T_C = 125^\circ\text{C}) \\ (i_F = 20 \text{ Amps, } T_C = 25^\circ\text{C}) \\ \end{subarray}$	VF	0.75 0.85 0.85 0.95	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, T <sub>C</sub> = 125°C) (Rated dc Voltage, T <sub>C</sub> = 25°C)	İR	6.0 0.1	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **ORDERING INFORMATION**

Device	Package	Shipping
MBR2080CTG	TO-220 (Pb-Free)	50 Units / Rail
MBR2090CTG	TO-220 (Pb-Free)	50 Units / Rail
MBR20100CTG	TO-220 (Pb-Free)	50 Units / Rail

<sup>1.</sup> The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

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Datasheet of MBR20100CT - DIODE ARRAY SCHOTTKY 100V TO220

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### MBR2080CTG, MBR2090CTG, MBR20100CTG

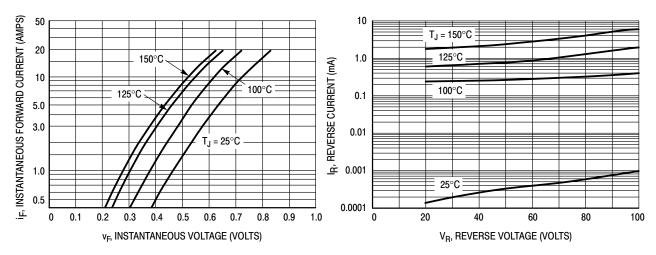


Figure 1. Typical Forward Voltage Per Diode

Figure 2. Typical Reverse Current Per Diode

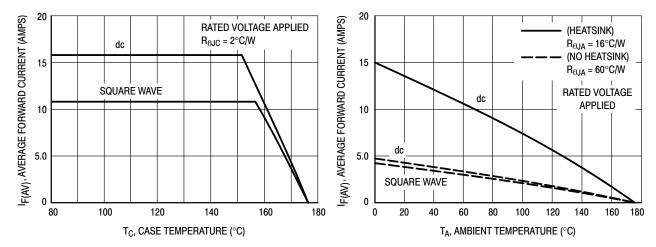


Figure 3. Typical Current Derating, Case, Per Leg

Figure 4. Typical Current Derating, Ambient, Per Leg

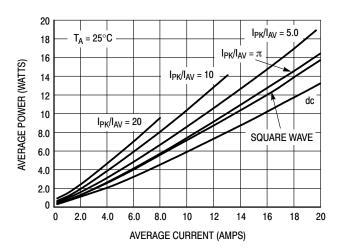


Figure 5. Average Power Dissipation and Average Current



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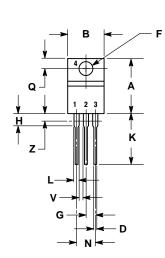
Datasheet of MBR20100CT - DIODE ARRAY SCHOTTKY 100V TO220

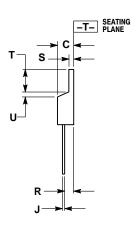
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#### PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH** 





- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. DIMENSION Z DEFINES A ZONE WHERE ALL CONTROLLING DIMENSION Z DEFINES A ZONE WHERE ALL CONTROLLING AND LEAD IRREGULARITIES ARE BODY AND LEAD IRREGULARITIES ARE

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.570	0.620	14.48	15.75	
В	0.380	0.415	9.66	10.53	
С	0.160	0.190	4.07	4.83	
D	0.025	0.038	0.64	0.96	
F	0.142	0.161	3.61	4.09	
G	0.095	0.105	2.42	2.66	
Н	0.110	0.161	2.80	4.10	
J	0.014	0.024	0.36	0.61	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.15	1.52	
N	0.190	0.210	4.83	5.33	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.15	1.39	
T	0.235	0.255	5.97	6.47	
U	0.000	0.050	0.00	1.27	
٧	0.045		1.15		
Z		0.080		2.04	

PIN 1. ANODE

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